

**DESCRIPTION:**

This document describes Aplus 256M x 72-bit 2GB DDR2-533 CL4 SDRAM (Synchronous DRAM) Registered ECC memory module. The components on this module include thirty-six 128M x 4-bit (4Banks) DDR2-533 SDRAM in FBGA packages. This 240-pin DIMM uses gold contact fingers and requires +1.8V. The electrical and mechanical specifications are as follows:

**FEATURES:**

- JEDEC standard 1.8V  $\pm$  0.1V Power supply
- All inputs and outputs SSTL\_1.8 compatible
- Max clock Freq: 267Mhz
- Double-data-rate architecture; two data transfers per clock cycle
- Bidirectional data strobe (DQS)
- Differential clock inputs (CK and CK)
- DLL aligns DQ and DQS transition with CK transition
- Programmable Read latency 4 (clock)
- Burst Length: 4,8 ( Interleave/nibble sequential )
- Programmable Burst type (sequential & interleave)
- Timing Reference: CL-tRCD-tRP (4-4-4)
- Edge aligned data output, center aligned data input
- Auto & Self refresh, 7.8us refresh interval (8K/64ms refresh)
- Error Check Correction ( ECC ) Capability
- High temperature self-refresh Entry enable features
- PASR ( Partial array self refresh )
- OCD ( Off-chip driver impedance adjustment )
- ODT ( On-die termination )
- Serial presence detect with EEPROM

**PERFORMANCE:**

Clock Cycle Time ( tCK )	3.75ns (min.) /8ns (max.)
Row Cycle Time ( tRC )	55ns (min.)
Refresh Row Cycle Time ( tRFC )	105ns (min.)
Row Active Time ( tRAS )	40ns (min.) /70,000ns (max.)
Operating Temperature	0°C ~ 85°C
Storage Temperature	-55°C ~ +100°C

